Vishay Semiconductors

Insulated Ultrafast Rectifier Module, 130 A



SOT-227

200 V

130 A

32 ns

Modules - Diode FRED Pt®

FEATURES

- Two fully independent diodes
- Fully insulated package
- Ultrafast, soft reverse recovery, with high operation junction temperature (T_J max. = 175 °C)
 RoHS
 COMPLIANT
- Low forward voltage drop
- Optimized for power conversion: welding and industrial SMPS applications
- Easy to use and parallel
- Industry standard outline
- Compliant to RoHS Directive 2002/95/EC
- · Designed and qualified for industrial level

DESCRIPTION

The VS-UFB130FA20 insulated modules integrate two state of the art ultrafast recovery rectifiers in the compact, industry standard SOT-227 package. The diodes structure, and its life time control, provide an ultrasoft recovery current shape, together with the best overall performance, ruggedness and reliability characteristics.

These devices are thus intended for high frequency applications in which the switching energy is designed not to be predominant portion of the total energy, such as in the output rectification stage of welding machines, SMPS, DC/DC converters. Their extremely optimized stored charge and low recovery current reduce both over dissipation in the switching elements (and snubbers) and EMI/RFI.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V _R		200	V		
Continuous forward current per diode	١ _F	T _C = 132 °C	65	٨		
Single pulse forward current per diode	I _{FSM}	T _C = 25 °C	890	A		
Maximum power dissipation per module	PD	T _C = 132 °C	119	W		
RMS isolation voltage	VISOL	Any terminal to case, t = 1 minute	2500	V		
Operating junction and storage temperatures	T _J , T _{Stg}		- 55 to 175	°C		

Pb-free



PRODUCT SUMMARY

 V_R

I_{F(AV)} per module at T_C = 126 °C

t_{rr}

Туре



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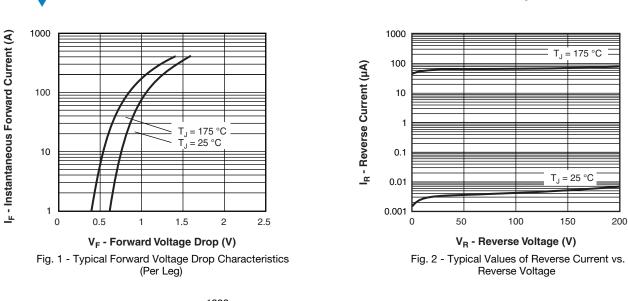
ELECTRICAL SPECIFICATIONS PER DIODE ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	200	-	-		
Forward voltage	V _{FM}	I _F = 60 A	-	0.96	1.13	V	
		I _F = 60 A, T _J = 175 °C	-	0.75	0.89		
Devene la clus es comment	I _{RM}	$V_{R} = V_{R}$ rated	-	2	50	μA	
Reverse leakage current		$T_J = 175 \text{ °C}, V_R = V_R \text{ rated}$	-	-	1	mA	
Junction capacitance	CT	V _R = 200 V	-	105	-	pF	

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONE	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}$	-	32	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	42	-	ns A	
		T _J = 125 °C]	-	68	-		
Peak recovery current I _{RRM}		T _J = 25 °C	I _F = 50 A dI _F /dt = 200 A/μs V _B = 100 V	-	4.0	-		
	IRRM	T _J = 125 °C		-	9.0	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C	• -	-	82	-	nC	
		T _J = 125 °C		-	295	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Junction to case, single leg conducting	Р		-	-	0.72		
Junction to case, both leg conducting	– R _{thJC}		-	-	0.36	°C/W	
Case to heatsink	R _{thCS}	Flat, greased surface	-	0.10	-		
Weight			-	30	-	g	
Mounting torque			-	1.3	-	Nm	
Case style			SOT-227				

VS-UFB130FA20

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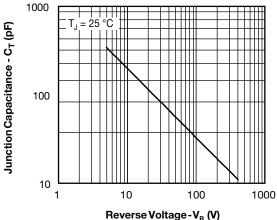


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

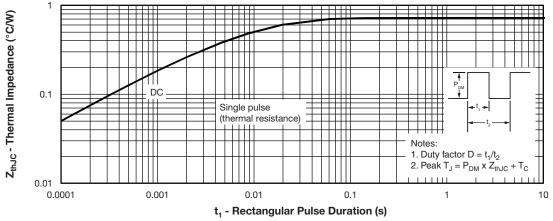


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

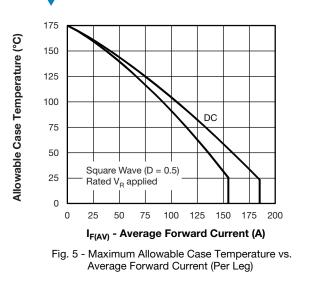
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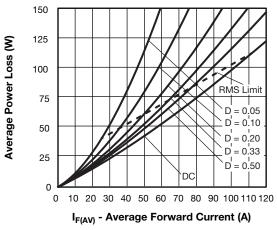
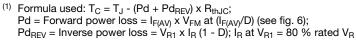
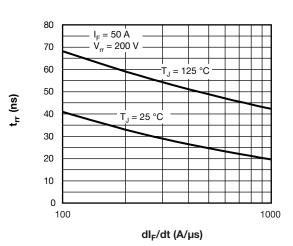


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

Note







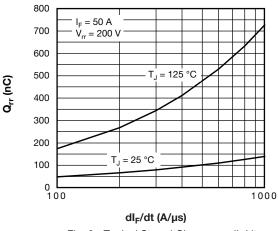


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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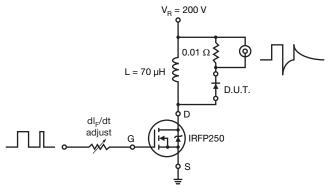
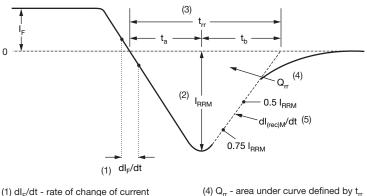


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- and I_{RRM}

$$Q_{rr} = \frac{\tau_{rr} \times \tau_{RRM}}{2}$$

- (5) $dI_{(rec)M}/dt$ peak rate of change of current during t_b portion of t_{rr}
- Fig. 10 Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	UF	В	130	F	Α	20
	1	2	3	4	5	6	7
	1 -	- Vishay Semiconductors product					
	2 -	- Ultrafast rectifier					
	3 -	Ultr	Ultrafast Pt diffused				
	4 -	Cur	rent rati	ng (130	= 130 A	A)	
	5 -	Circ	uit conf	iguratior	ר (2 sep	arate di	odes, p
	6 -	Pac	kage in	dicator (SOT-22	27 stanc	lard iso
	7 -	Volt	age rati	ng (20 =	= 200 V))	

CIRCUIT CONFIGURATION							
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING					
2 separate diodes, parallel pin-out	F	Lead Assignment					

LINKS TO RELATED DOCUMENTS						
Dimensions www.vishay.com/doc?95423						
Packaging information	www.vishay.com/doc?95425					



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